



VCx-808C300A

808nm 300mW CW VCSEL Diode

Data Sheet

Features

- 808nm VCSEL diode
- Output power: 300mW (CW)
- Available in SMD or TO-can package options

Applications

- 3D sensing systems
- Industrial and automotive LiDAR
- IR (infrared) illumination
- Range finding sensors
- Medical and therapeutic equipment
- Solid-state laser pump sources

Ordering Information

Part Number	Description
VC20A-808C300A	808nm 300mW CW VCSEL Diode, SMD 2016 Package
VCT5-808C300A	808nm 300mW CW VCSEL Diode, TO-56 Package

* Additional package configurations may be available upon request.

Absolute Maximum Ratings

Parameters	Symbol	Rating	Unit	Conditions
Case Operating Temperature	Top	-40 to 85	°C	
Storage Temperature	Tstg	-40 to 105	°C	
Reflow Soldering Temperature	Tsol	260	°C	10 seconds
Reverse Voltage	Vr	5	V	
Maximum Continuous Current	I _{max}	600	mA	
ESD Exposure (Human Body) Model	ESD	2K-4K (Class 2)	V	
ESD Exposure (Machine) Model	ESD	200-400 (Class B)	V	

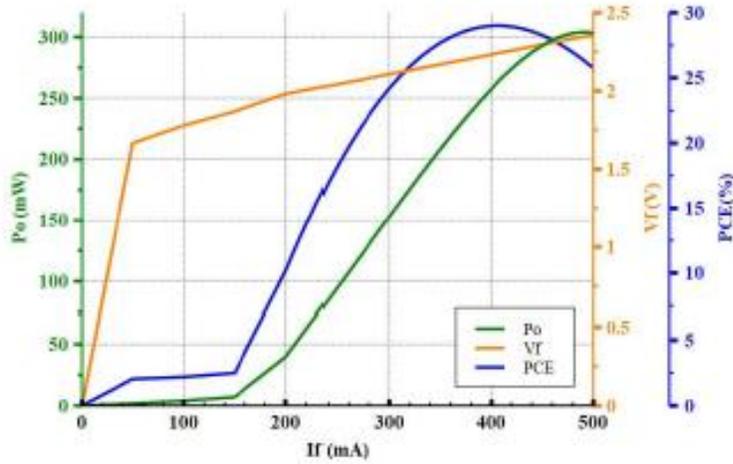
Electrical-Optical Characteristics (T_{op}=25°C, CW Mode)

Parameters	Symbol	Min.	Typ.	Max.	Unit	Conditions
Optical Output Power	P _o	-	300	-	mW	I _F =470mA
Threshold Current	I _{th}	-	110	-	mA	
Forward Current	I _F	-	470	-	mA	
Power Conversion Efficiency	PCE	-	28	-	%	
Slope Efficiency	η	-	0.85	-	mW/mA	
Peak Wavelength	λ _P	800	808	816	nm	P _o =300mW
Forward Voltage	V _f	-	2.4	-	V	I _F =470mA
Emission Area		-	294x278		um ²	
Series Resistance	R _s	-	1.6	-	Ohm	I _F =470mA
Beam Angle	(1/e ²)		25		Deg	I _F =470mA
	FWHM		20			
Wavelength Temperature Drift	Δλ _p / ΔT	-	0.07	-	nm/°C	I _F =470mA
Soldering Temperature	Tsol			260	°C	10 seconds

Note: Electro-optical characteristics with a package or diffuser would require further evaluation. Values are based on limited sample size and estimated values.

Typical Characteristics

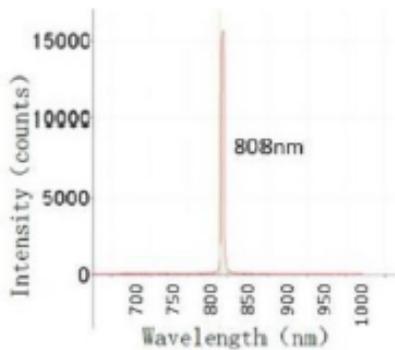
LIV Graph



Notes:

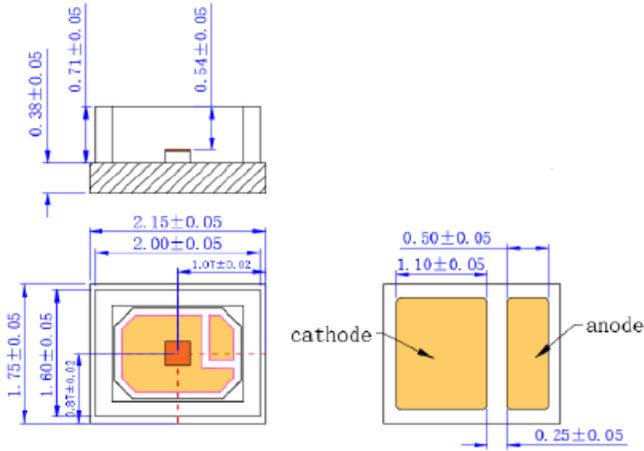
1. LIV graph was measured at 25°C (left); power output, voltage and power conversion efficiency
2. Variation trend with changed operating temperature (right, normalized).
3. Forward voltage (V_F) measurement allowance is $\pm 0.1V$.
4. Peak wavelength (λ_p) measurement allowance is $\pm 1.5nm$.
5. Others measurement allowance is $\pm 10\%$.

Intensity vs. Wavelength

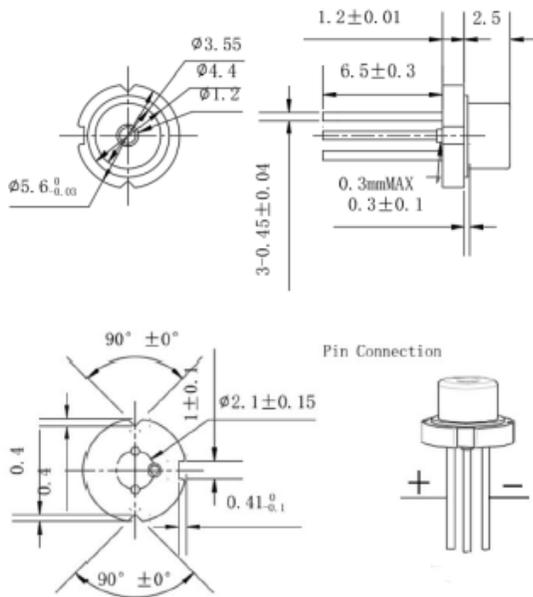


Outline Dimensions (unit: mm)

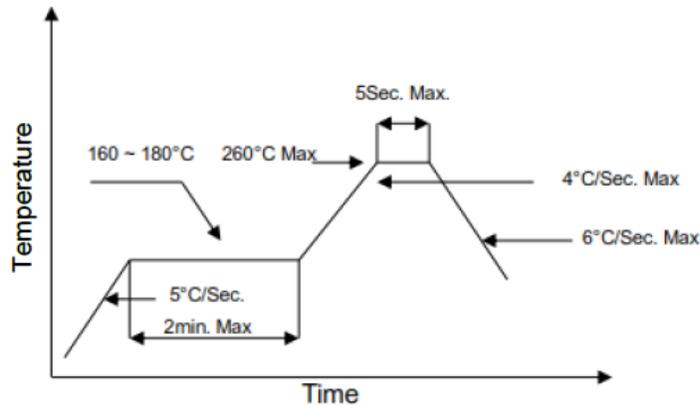
SMD 2016 Package



TO-56 Package



SMT Reflow Soldering Curve



Note: Reflow soldering can be operated only one time. During the temperature ramp-up, no forces may be exerted on the LD which would deform or damage them. After soldering is completed, please do not process until the product temperature ramps down to room temperature.

Additional Notes

1. Stresses exceeding those listed in Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress limits only and do not imply functional operation under such conditions. Exposure to conditions beyond recommended operating limits may affect device reliability.
2. Operation at or near maximum ratings may degrade performance and may create potential safety risks, including device failure.
3. The device is sensitive to electrostatic discharge (ESD). Proper ESD precautions, including grounded wrist straps, antistatic work surfaces, and ESD-safe handling procedures, must be followed during handling and assembly.
4. Adequate thermal management must be provided. The VCSEL device should be properly mounted to ensure efficient heat transfer to the package or system thermal path to maintain stable optical performance.
5. Avoid direct exposure of laser radiation to human eyes or skin. Follow applicable laser safety regulations and system-level safety design practices.
6. The emitting surface of the VCSEL should not be touched or contaminated. Mechanical contact or contamination may degrade optical performance or damage the device.
7. Use appropriate pick-and-place handling tools, such as ceramic or ESD-safe vacuum nozzles, to prevent mechanical or electrostatic damage during assembly.
8. Specifications are subject to change without notice.